FM2H100-MS-Q1

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FM2H100-MS-Q1

2.0A Surface Mount High Junction Temperature Schottky Barrier Rectifiers 100V

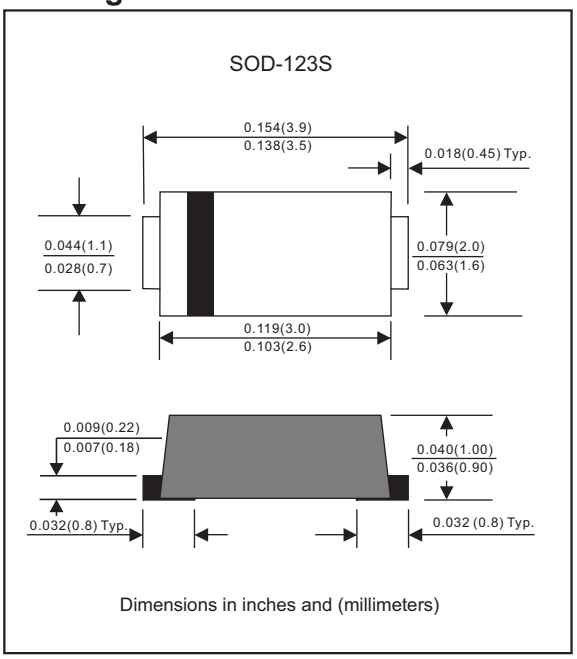
Features

- High junction temperature 175°C
- Very low profile typical height of 0.95mm
- Tiny plastic SMD package
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- Silicon epitaxial planar chip, metal silicon junction
- Lead-free parts meet RoHS requirements
- Qualified to AEC-Q101 standards for high reliability
- Suffix "-H" indicates Halogen free parts, ex. FM2H100-MS-Q1-H

Mechanical data

- Epoxy : UL94-V0 rated flame retardant
- Case : Molded plastic, SOD-123S/MINI SMA
- Terminals :Plated terminals, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any
- Weight : Approximated 0.0155 gram

Package outline



Dimensions in inches and (millimeters)

Maximum ratings (AT T_A=25°C unless otherwise noted)

Parameter	Symbols	FM2H100-MS-Q1	Units
Maximum repetitive peak reverse voltage	V_{RRM}	100	Volts
Maximum RMS voltage	V_{RMS}	70	Volts
Maximum continuous reverse voltage	V_R	100	Volts
Maximum average forward rectified current	I_O	2.0	Amps
Non-repetitive peak forward surge current 8.3ms single half sine-wave	I_{FSM}	30	Amps
Typical junction capacitance (Note 1)	C_J	25	pF
Operating junction temperature range	T_J	-55 to +175	°C
Storage temperature range	T_{STG}	-65 to +175	°C

Electrical characteristics (AT T_A=25°C unless otherwise noted)

Parameter	Symbols	Typ.	Max.	Units
Instantaneous forward voltage at I_F=1.0A T_J=25°C I_F=2.0A T_J=25°C	V_F	0.825 0.895	- 0.95	Volts Volts
Reverse leakage current at rated V_R T_J=25°C T_J=125°C	I_R	0.01 15	1.0 300	μA μA

Thermal characteristics

Parameter	Symbols	FM2H100-MS-Q1	Units
Typical thermal resistance junction to ambient (Note 2)	$R_{\theta JA}$	80	°C/W
Typical thermal resistance junction to case (Note 2)	$R_{\theta JC}$	40	°C/W

Notes1: Measured at 1MHz and applied reverse voltage of 4.0V D.C
2: Mounted on FR-4 PCB copper, minimum recommended pad layout

Rating and characteristic curves (FM2H100-MS-Q1)

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

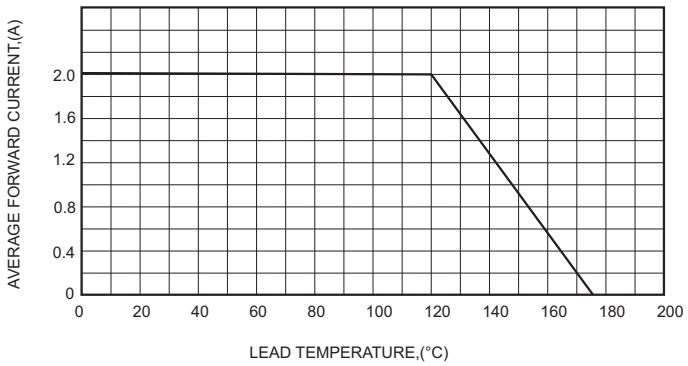


FIG.2-TYPICAL FORWARD CHARACTERISTICS

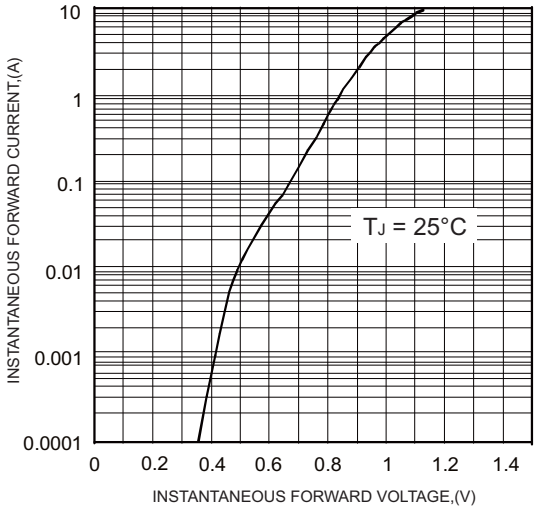


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

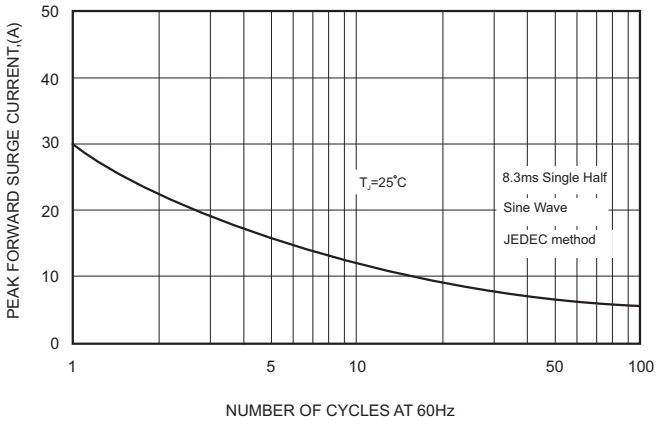


FIG.4-TYPICAL JUNCTION CAPACITANCE

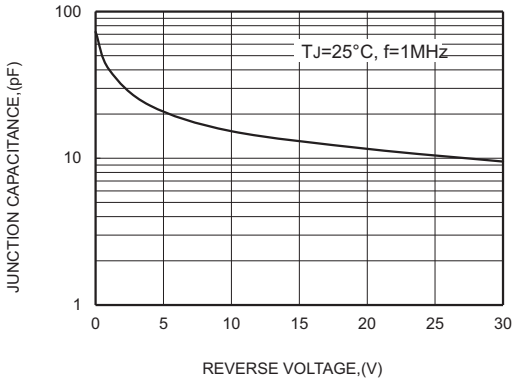
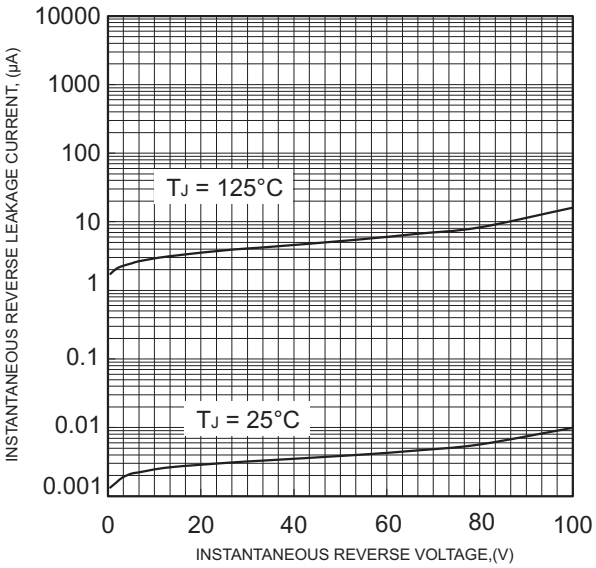


FIG.5 - TYPICAL REVERSE CHARACTERISTICS



FM2H100-MS-Q1

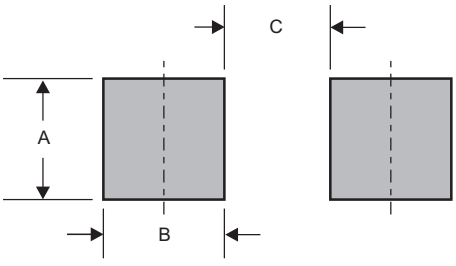
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

Marking

Type number	Marking code
FM2H100-MS-Q1	20H

Suggested solder pad layout



Dimensions in inches and (millimeters)

PACKAGE	A	B	C
SOD-123S	0.044 (1.10)	0.040 (1.00)	0.079 (2.00)

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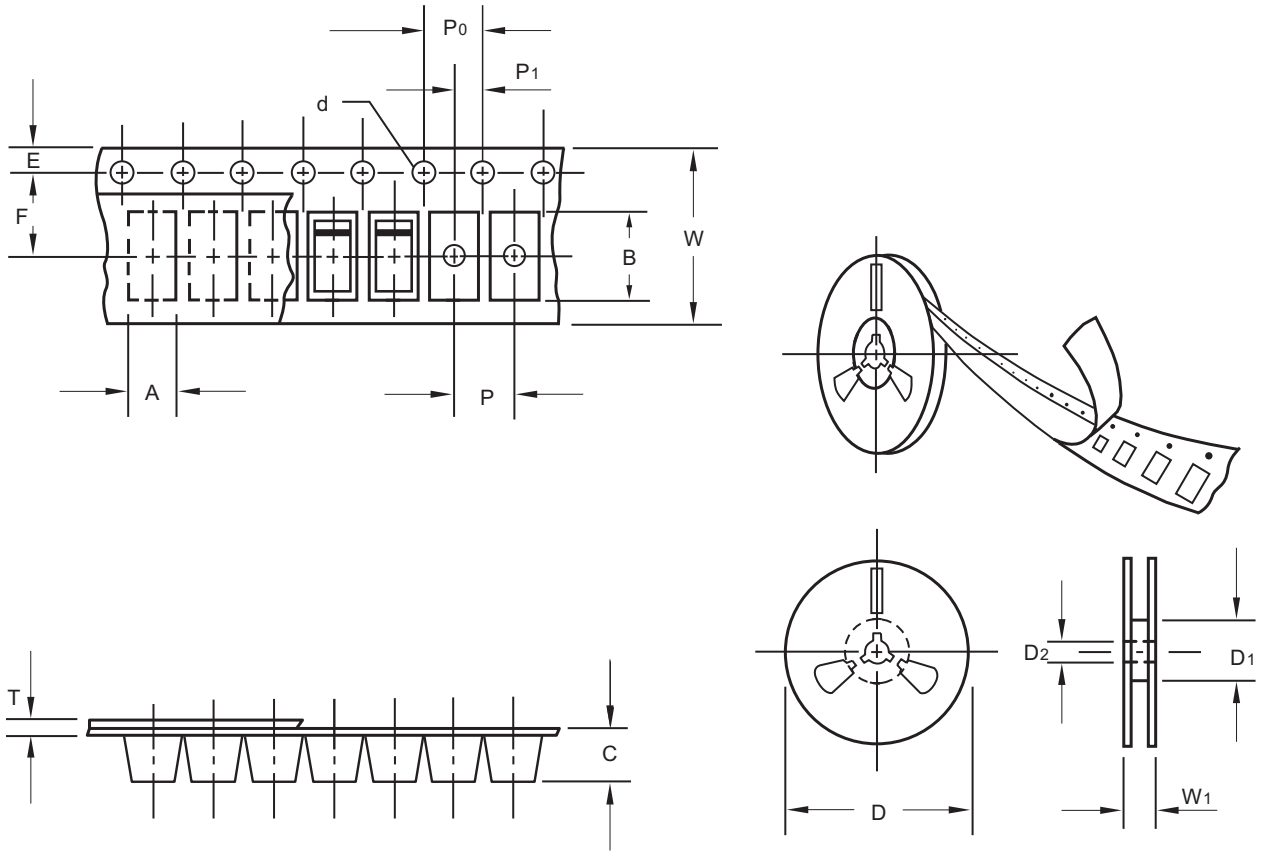
Packing information



unit:mm

Item	Symbol	Tolerance	SOD-123S
Carrier width	A	0.1	2.00
Carrier length	B	0.1	3.85
Carrier depth	C	0.1	1.10
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	-
13" Reel inner diameter	D_1	min	-
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D_1	min	62.00
Feed hole diameter	D_2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P_0	0.1	4.00
Embossment center	P_1	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	8.00
Reel width	W_1	1.0	11.40

Note:Devices are packed in accor dance with EIA standar RS-481-A and specifications listed above.

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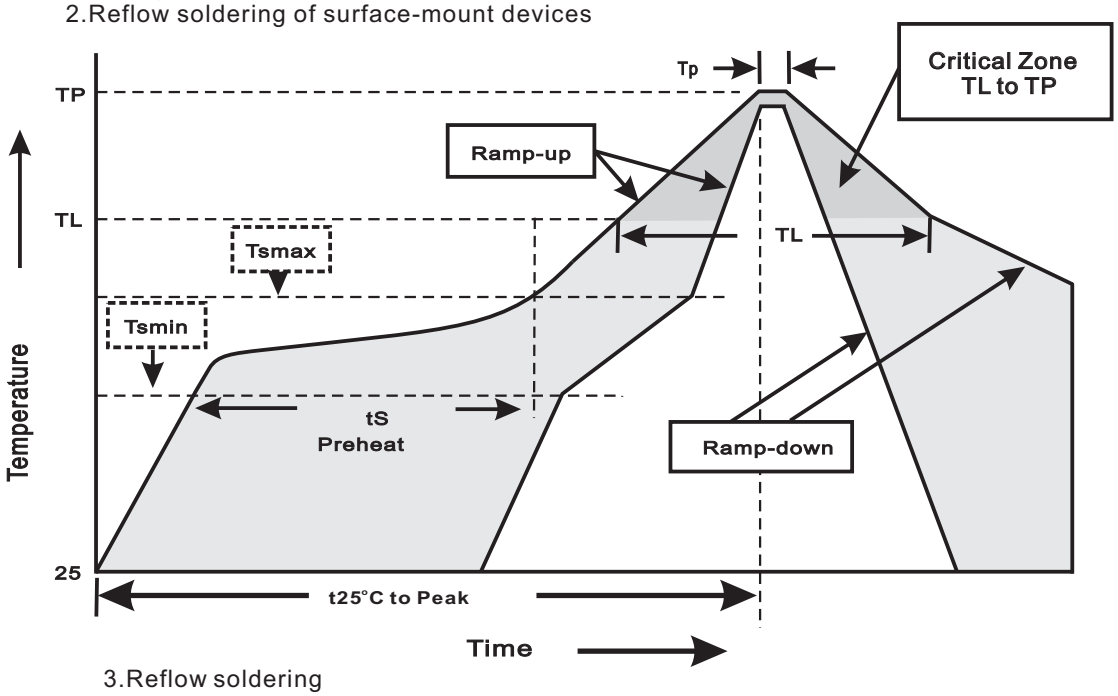
Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOD-123S	7"	3,000	4.0	30,000	183*123*183	178	382*257*387	240,000	9.5

Suggested thermal profiles for soldering processes

1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T_L to T_P)	<3°C/sec
Preheat -Temperature Min(Tsmin) -Temperature Max(Tsmax) -Time(min to max)(t_s)	 150°C 200°C 60~120sec
Tsmax to T_L -Ramp-upRate	 <3°C/sec
Time maintained above: -Temperature(T_L) -Time(t_L)	 217°C 60~260sec
Peak Temperature(T_P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t_P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes

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High reliability test capabilities

Item Test	Conditions	Reference
1. MSL Preconditioning	24hr bake@125℃+168hrs@85℃ /85%RH+3xIR@260℃+1flux immersion+alcohol+DI H2O rinse	JESD22-A113
2. Operation Life	Ta=25℃,Rated Current (Io=Io max.)Test Duration:1000hrs	MIL-STD-750E METHOD 1027.3
3. High Temperature Reverse Bias	80% Rated VR (Tj=Tj max.)Test Duration:1000hrs	JESD22-A108
4. High Temperature Storage Life	Ta=125℃ Test Duration:1000hrs	JESD22 A-103
5. Temperature Cycle	-55℃(15min) to 150℃(15min)Test Cycles:1000cycles	JESD22 A-104
6. Autoclave	P=2atm Ta=121℃ RH=100% Test Duration:96hrs	JESD22 A-102
7. Intermittent Operational Life	Ta=25℃,On/Io Max. 2min, Off/2min, Test Cycles:15000cycles	MIL-STD-750E METHOD 1037
8. Solderability	245±5℃ for 5sec	J-STD-002
9. Moisture Resistance	Ta=85℃/85% Relative humidity Test Duration:1000hrs	MIL-STD-750E METHOD 1021.2
10. Resistance To Solder Heat	260±5℃ for 10sec	JESD22 B-106
11. High Temperature High Humidity Reverse Bias	Ta=85℃, 85%RH, with device reverse biased at 80% of rated breakdown voltage up to a maximum of 100V or limit of chamber Test Duration:1000hrs	JESD22-A101